

FORM 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION (Use several sheets if necessary)		Docket Number: 10873.1944USWO	Application Number: 10/598095
		Applicant: KITAOKA, et al.	
		Filing Date: August 17, 2006	Group Art Unit: 1792

FOREIGN PATENT DOCUMENTS

DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
					YES	NO
/F.H./	2005/121415	December, 2005	WIPO			
/F.H./	2008-501600	January, 2008	Japan			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Kawamura, et al., "Novel Liquid Phase Epitaxy (LPE) Growth Method for Growing Large GaN Single Crystals: Introduction of the Flux Film Coated-Liquid Phasc Epitaxy (FFC-LPE) Method", Jpn. J. Appl. Phys. vol. 42 (2003), pp. L879-L881

53148

Customer Number

EXAMINER /Felisa Hiteshew/ DATE CONSIDERED 08/12/2008

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.